Ordering number:ENN5817A

NPN Triple Diffused Planar Silicon Transistor

2SC5417LS

Inverter Lighting Applications

Features

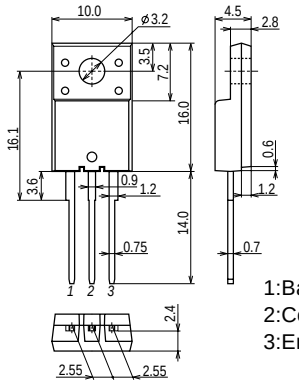
- High breakdown voltage.
- High reliability (Adoption of HVP process).
- Adoption of MBIT process.

Package Dimensions

unit:mm

2079D

[2SC5417]



1:Base
2:Collector
3:Emitter

SANYO:TO-220FI (LS)

Specifications

Absolute Maximum Ratings at Ta = 25˚C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		1200	V
Collector-to-Emitter Voltage	V_{CEO}		600	V
Emitter-to-Base Voltage	V_{EBO}		9	V
Collector Current	I_C		3	A
Collector Current (pulse)	I_{CP}		6	A
Collector Dissipation	P_C		2	W
		Tc=25˚C	25	W
Junction Temperature	Tj		150	˚C
Storage Temperature	Tstg		–55 to +150	˚C

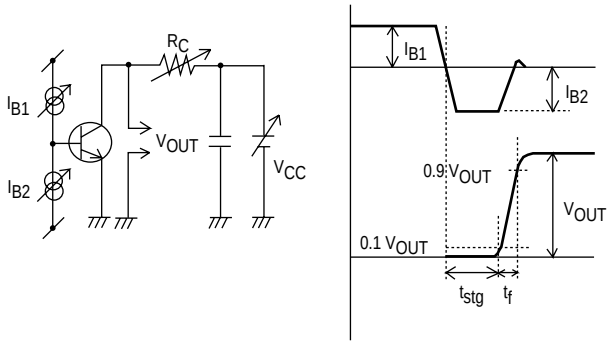
Electrical Characteristics at Ta=25˚C

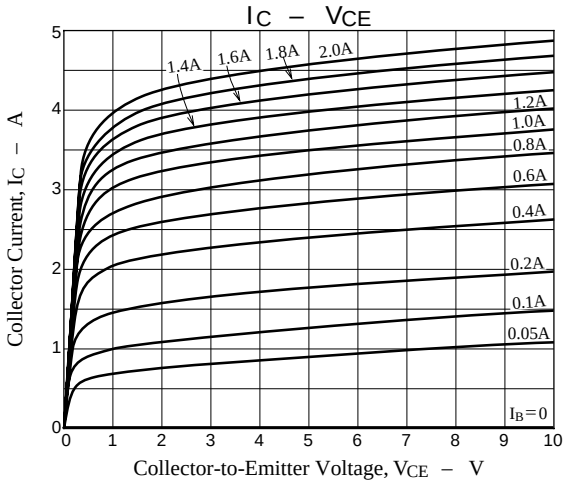
Parameter	Symbol	Conditons	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	V_{CB}=600V, I_E=0			10	μA
Collector Cutoff Current	I_{CES}	V_{CE}=1200V, R_{BE}=0			1.0	mA
Collector Sustain Voltage	$V_{CEO(sus)}$	I_C=100mA, I_B=0	600			V
Emitter Cutoff Current	I_{EBO}	V_{EB}=9V, I_C=0			1.0	mA
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	I_C=1.5A, I_B=0.3A			1.0	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	I_C=1.5A, I_B=0.3A			1.5	V
DC Current Gain	$h_{FE}1$	V_{CE}=5V, I_C=0.1A	30	40	50	
	$h_{FE}2$	V_{CE}=5V, I_C=1.0A	10			
Storage Time	t_{stg}	I_C=1.5A, I_{B1}=0.3A, I_{B2}=–0.6A			2.5	μs
Fall Time	t_f	I_C=1.5A, I_{B1}=0.3A, I_{B2}=–0.6A			0.15	μs

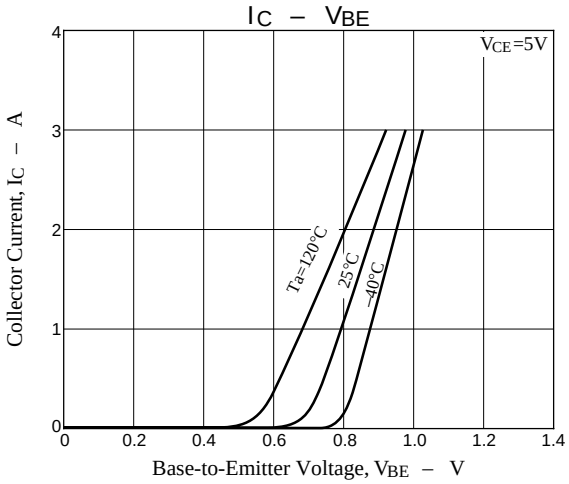
SANYO Electric Co.,Ltd. Semiconductor Company

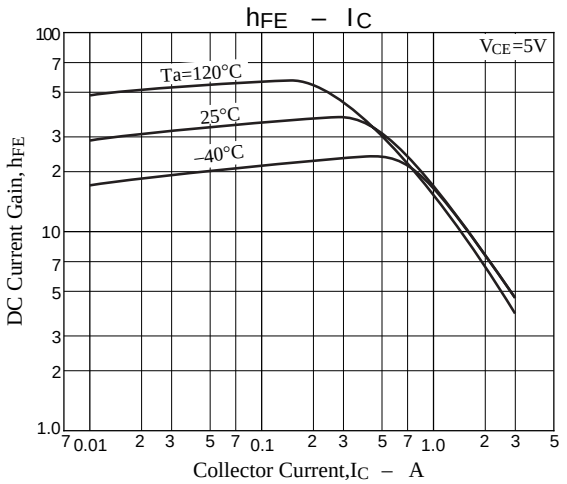
TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

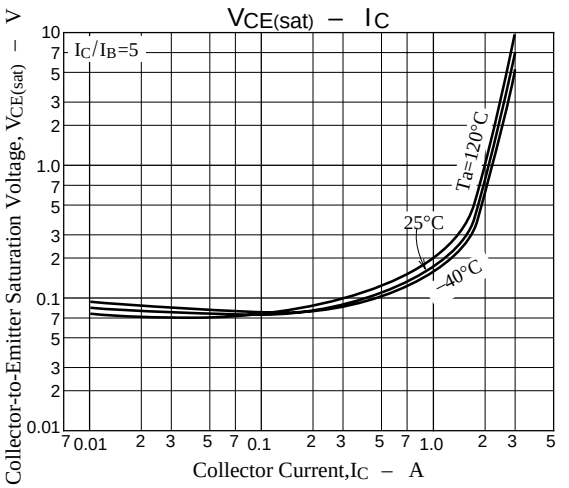
Switching Time Test Circuit

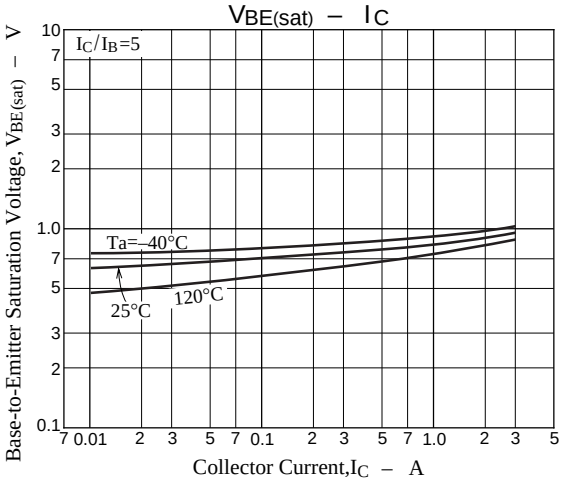


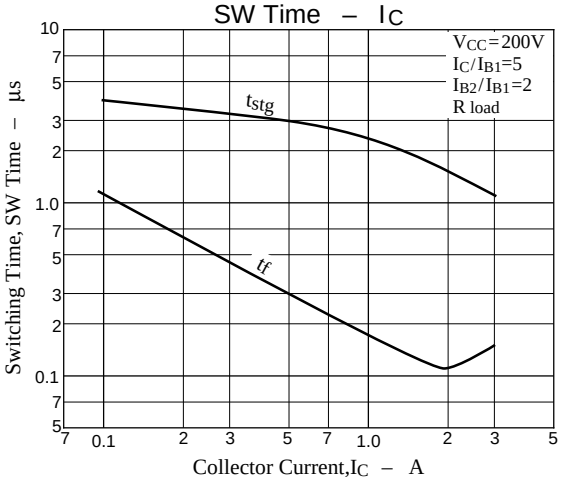


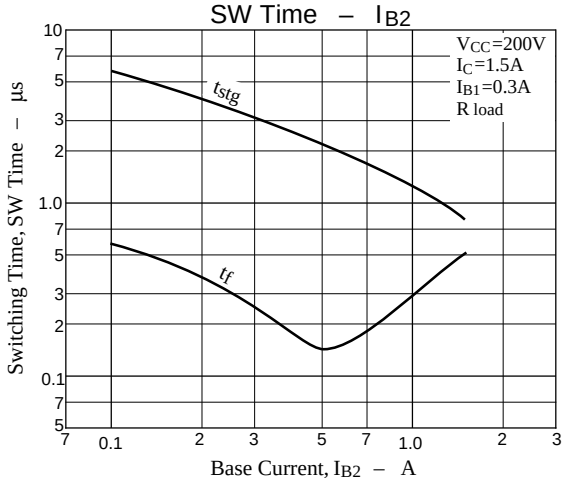


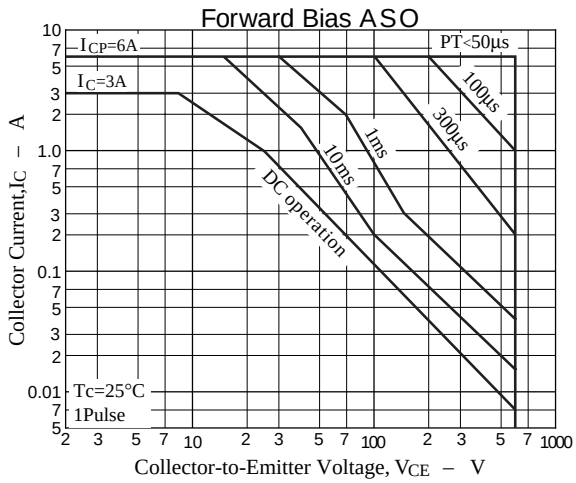


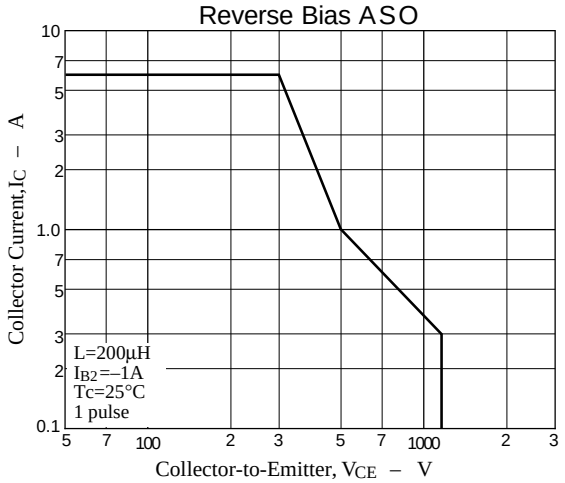


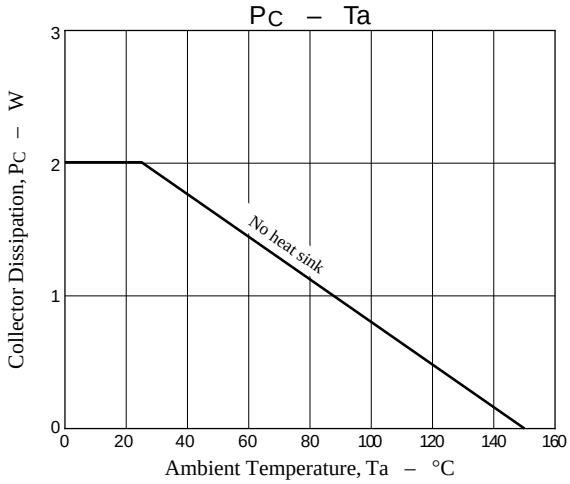


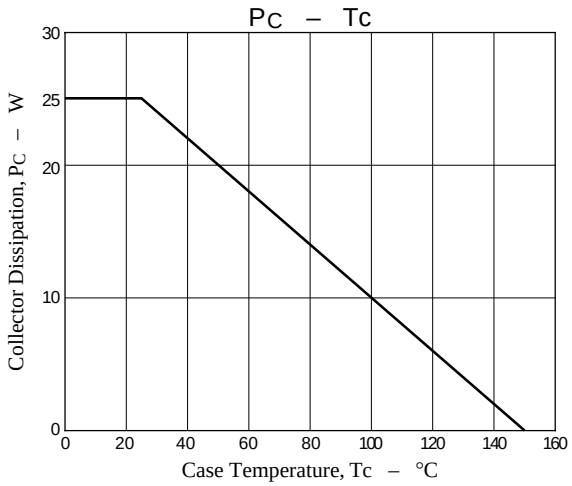



SW Time – IB2
VCC=200V
IC=1.5A
IB1=0.3A
R load
tstg
tf
Switching Time, SW Time – µs
Base Current, IB2 – A


Forward Bias ASO
ICP=6A
IC=3A
PT<50µs
100µs
300µs
1ms
10ms
DC operation
Tc=25°C
1Pulse
Collector Current,IC – A
Collector-to-Emitter Voltage, VCE – V


Reverse Bias ASO
L=200µH
IB2=–1A
Tc=25°C
1 pulse
Collector Current,IC – A
Collector-to-Emitter, VCE – V


PC – Ta
No heat sink
Collector Dissipation, PC – W
Ambient Temperature, Ta – °C


PC – Tc
Collector Dissipation, PC – W
Case Temperature, Tc – °C